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Applications of "<u>Embedded - Microcontrollers</u>"

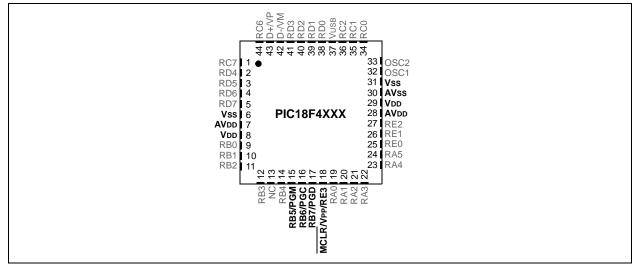
Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	40MHz
Connectivity	I <sup>2</sup> C, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, HLVD, POR, PWM, WDT
Number of I/O	36
Program Memory Size	64KB (32K x 16)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	3.8K x 8
Voltage - Supply (Vcc/Vdd)	4.2V ~ 5.5V
Data Converters	A/D 13x10b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	44-TQFP
Supplier Device Package	44-TQFP (10x10)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic18f4610-i-pt

The following devices are included in 44-pin QFN parts:

- PIC18F4221
- PIC18F4321
- PIC18F4410
- PIC18F4420
- PIC18F4423
- PIC18F4450
- PIC18F4455
- PIC18F4458
- PIC18F4480
- PIC18F4510
- PIC18F4520
- PIC18F4515

- PIC18F4523
- PIC18F4525
- PIC18F4550
- PIC18F4553
- PIC18F4580
- PIC18F4585
- PIC18F4610
- PIC18F4620
- PIC18F4680
- PIC18F4682
- PIC18F4685

#### FIGURE 2-5: 44-PIN QFN



#### 2.3 **Memory Maps**

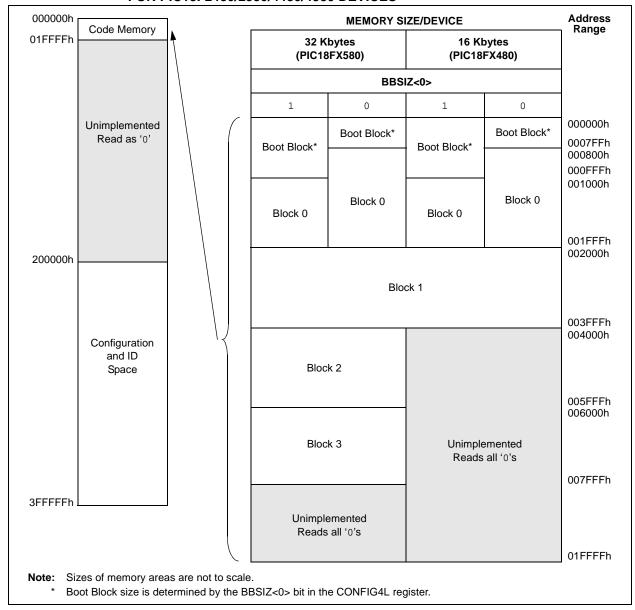
For PIC18FX6X0 devices, the code memory space extends from 0000h to 0FFFFh (64 Kbytes) in four 16-Kbyte blocks. For PIC18FX5X5 devices, the code memory space extends from 0000h to 0BFFFFh (48 Kbytes) in three 16-Kbyte blocks. Addresses, 0000h through 07FFh, however, define a "Boot Block" region that is treated separately from Block 0. All of these blocks define code protection boundaries within the code memory space.

The size of the Boot Block in PIC18F2585/2680/4585/4680 devices can be configured as 1, 2 or 4K words (see Figure 2-6). This is done through the BBSIZ<1:0> bits in the Configuration register, CONFIG4L. It is important to note that increasing the size of the Boot Block decreases the size of Block 0.

TABLE 2-6: IMPLEMENTATION OF CODE MEMORY

Device	Code Memory Size (Bytes)
PIC18F2480	000000h 003EEEh (16K)
PIC18F4480	000000h-003FFFh (16K)
PIC18F2580	000000h 007EEEh (22K)
PIC18F4580	000000h-007FFFh (32K)

FIGURE 2-10: MEMORY MAP AND THE CODE MEMORY SPACE FOR PIC18F2480/2580/4480/4580 DEVICES



For PIC18F2221/4221 devices, the code memory space extends from 0000h to 00FFFh (4 Kbytes) in one 4-Kbyte block. For PIC18F2321/4321 devices, the code memory space extends from 0000h to 01FFFh (8 Kbytes) in two 4-Kbyte blocks. Addresses, 0000h through 07FFh, however, define a variable "Boot Block" region that is treated separately from Block 0. All of these blocks define code protection boundaries within the code memory space.

In addition to the code memory space, there are three blocks that are accessible to the user through Table Reads and Table Writes. Their locations in the memory map are shown in Figure 2-12.

Users may store identification information (ID) in eight ID registers. These ID registers are mapped in addresses, 200000h through 200007h. The ID locations read out normally, even after code protection is applied.

Locations, 300000h through 30000Dh, are reserved for the Configuration bits. These bits select various device options and are described in **Section 5.0 "Configuration Word"**. These Configuration bits read out normally, even after code protection.

Locations, 3FFFFEh and 3FFFFFh, are reserved for the Device ID bits. These bits may be used by the programmer to identify what device type is being programmed and are described in **Section 5.0 "Configuration Word"**. These Device ID bits read out normally, even after code protection.

#### 2.3.1 MEMORY ADDRESS POINTER

Memory in the address space, 0000000h to 3FFFFFh, is addressed via the Table Pointer register, which is comprised of three pointer registers:

- TBLPTRU at RAM address 0FF8h
- TBLPTRH at RAM address 0FF7h
- · TBLPTRL at RAM address 0FF6h

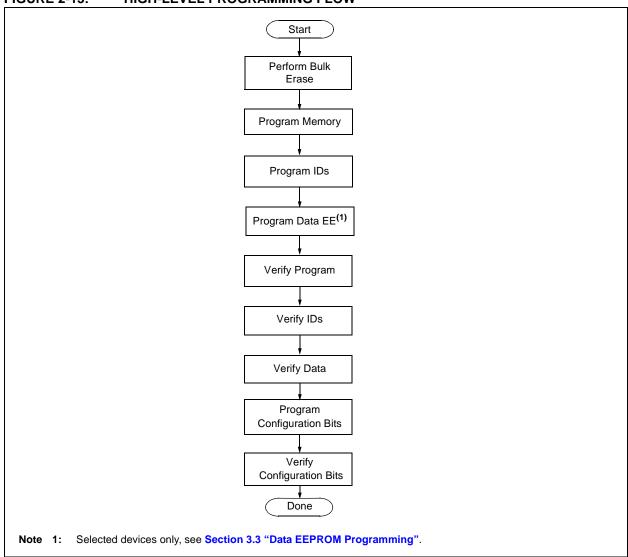
TBLPTRU	TBLPTRH	TBLPTRL
Addr[21:16]	Addr[15:8]	Addr[7:0]

The 4-bit command, '0000' (core instruction), is used to load the Table Pointer prior to using many read or write operations.

### 2.4 High-Level Overview of the Programming Process

Figure 2-13 shows the high-level overview of the programming process. First, a Bulk Erase is performed. Next, the code memory, ID locations and data EEPROM are programmed (selected devices only, see **Section 3.3 "Data EEPROM Programming"**). These memories are then verified to ensure that programming was successful. If no errors are detected, the Configuration bits are then programmed and verified.

FIGURE 2-13: HIGH-LEVEL PROGRAMMING FLOW



#### 2.6 Entering and Exiting Low-Voltage ICSP Program/Verify Mode

When the LVP Configuration bit is '1' (see Section 5.3 "Single-Supply ICSP Programming"), the Low-Voltage ICSP mode is enabled. As shown in Figure 2-16, Low-Voltage ICSP Program/Verify mode is entered by holding PGC and PGD low, placing a logic high on PGM and then raising  $\overline{\text{MCLR}/\text{VPP/RE3}}$  to VIH. In this mode, the RB5/PGM pin is dedicated to the programming function and ceases to be a general purpose I/O pin. Figure 2-17 shows the exit sequence.

The sequence that enters the device into the Program/Verify mode places all unused I/Os in the high-impedance state.

FIGURE 2-16: ENTERING LOW-VOLTAGE PROGRAM/VERIFY MODE

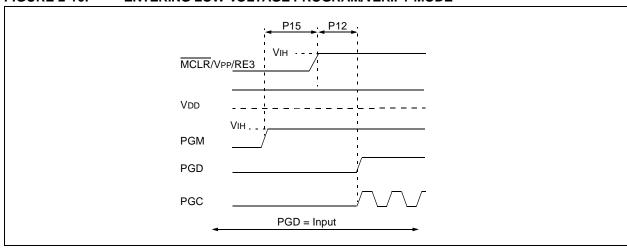
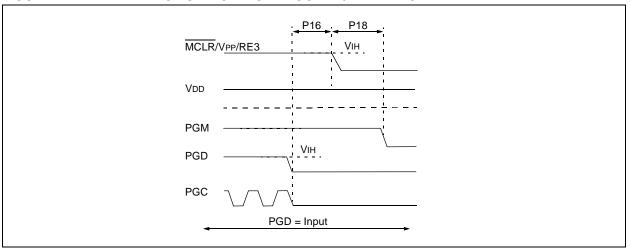


FIGURE 2-17: EXITING LOW-VOLTAGE PROGRAM/VERIFY MODE



#### 2.8 Dedicated ICSP/ICD Port (44-Pin TQFP Only)

The PIC18F4455/4458/4550/4553 44-pin TQFP devices are designed to support an alternate programming input: the dedicated ICSP/ICD port. The primary purpose of this port is to provide an alternate In-Circuit Debugging (ICD) option and free the pins (RB6, RB7 and  $\overline{MCLR}$ ) that would normally be used for debugging the application. In conjunction with ICD capability, however, the dedicated ICSP/ICD port also provides an alternate port for ICSP.

Setting the ICPRT Configuration bit enables the dedicated ICSP/ICD port. The dedicated ICSP/ICD port functions the same as the default ICSP/ICD port; however, alternate pins are used instead of the default pins. Table 2-10 identifies the functionally equivalent pins for ICSP purposes:

The dedicated ICSP/ICD port is an alternate port. Thus, ICSP is still available through the default port even though the ICPRT Configuration bit is set. When the VIH is seen on the MCLR/VPP/RE3 pin prior to applying VIH to the ICRST/ICVPP pin, then the state of the ICRST/ICVPP pin is ignored. Likewise, when the VIH is seen on ICRST/ICVPP prior to applying VIH to MCLR/VPP/RE3, then the state of the MCLR/VPP/RE3 pin is ignored.

**Note:** The ICPRT Configuration bit can only be programmed through the default ICSP port. Chip Erase functions through the dedicated ICSP/ICD port do not affect this bit.

When the ICPRT Configuration bit is set (dedicated ICSP/ICD port enabled), the NC/ICPORTS pin must be tied to either VDD or VSS.

The ICPRT Configuration bit must be maintained clear for all 28-pin and 40-pin devices; otherwise, unexpected operation may occur.

TABLE 2-10: ICSP™ EQUIVALENT PINS

Pin Name	During Programming									
Pili Name	Pin Name	Pin Type	Dedicated Pins	Pin Description						
MCLR/Vpp/RE3	VPP	Р	NC/ICRST/ICVPP	Programming Enable						
RB6	PGC	I	NC/ICCK/ICPGC	Serial Clock						
RB7	PGD	I/O	NC/ICDT/ICPGD	Serial Data						

**Legend:** I = Input, O = Output, P = Power

#### 3.0 DEVICE PROGRAMMING

Programming includes the ability to erase or write the various memory regions within the device.

In all cases, except high-voltage ICSP Bulk Erase, the EECON1 register must be configured in order to operate on a particular memory region.

When using the EECON1 register to act on code memory, the EEPGD bit must be set (EECON1<7> = 1) and the CFGS bit must be cleared (EECON1<6> = 0). The WREN bit must be set (EECON1<2> = 1) to enable writes of any sort (e.g., erases) and this must be done prior to initiating a write sequence. The FREE bit must be set (EECON1<4> = 1) in order to erase the program space being pointed to by the Table Pointer. The erase or write sequence is initiated by setting the WR bit (EECON1<1> = 1). It is strongly recommended that the WREN bit only be set immediately prior to a program erase.

#### 3.1 ICSP Erase

#### 3.1.1 HIGH-VOLTAGE ICSP BULK ERASE

Erasing code or data EEPROM is accomplished by configuring two Bulk Erase Control registers located at 3C0004h and 3C0005h. Code memory may be erased, portions at a time, or the user may erase the entire device in one action. Bulk Erase operations will also clear any code-protect settings associated with the memory block being erased. Erase options are detailed in Table 3-1. If data EEPROM is code-protected (CPD = 0), the user must request an erase of data EEPROM (e.g., 0084h as shown in Table 3-1).

TABLE 3-1: BULK ERASE OPTIONS

Description	Data (3C0005h:3C0004h)
Chip Erase	3F8Fh
Erase Data EEPROM <sup>(1)</sup>	0084h
Erase Boot Block	0081h
Erase Configuration Bits	0082h
Erase Code EEPROM Block 0	0180h
Erase Code EEPROM Block 1	0280h
Erase Code EEPROM Block 2	0480h
Erase Code EEPROM Block 3	0880h
Erase Code EEPROM Block 4	1080h
Erase Code EEPROM Block 5	2080h

Note 1: Selected devices only, see Section 3.3 "Data EEPROM Programming".

The actual Bulk Erase function is a self-timed operation. Once the erase has started (falling edge of the 4th PGC after the NOP command), serial execution will cease until the erase completes (Parameter P11). During this time, PGC may continue to toggle but PGD must be held low.

The code sequence to erase the entire device is shown in Table and the flowchart is shown in Figure 3-1.

Note: A Bulk Erase is the only way to reprogram code-protect bits from an ON state to an OFF state.

TABLE 3-3: ERASE CODE MEMORY CODE SEQUENCE

Step 1: Direct access to code memory and enable writes.           0000         8E A6         BSF EECON1, EEPGD           0000         9C A6         BCF EECON1, CFGS           0000         84 A6         BSF EECON1, WREN           Step 2: Point to first row in code memory.           0000         6A F8         CLRF TBLPTRU           0000         6A F7         CLRF TBLPTRH           0000         6A F6         CLRF TBLPTRL           Step 3: Enable erase and erase single row.           0000         88 A6         BSF EECON1, FREE           0000         82 A6         BSF EECON1, WR           0000         00 00         NOP - hold PGC high for time P9 and low for time P10.	4-Bit Command	Data Payload	Core Instruction
0000         9C A6         BCF         EECON1, CFGS           0000         84 A6         BSF         EECON1, WREN           Step 2: Point to first row in code memory.           0000         6A F8         CLRF         TBLPTRU           0000         6A F7         CLRF         TBLPTRH           0000         6A F6         CLRF         TBLPTRL           Step 3: Enable erase and erase single row.           0000         88 A6         BSF         EECON1, FREE           0000         82 A6         BSF         EECON1, WR	Step 1: Direct ac	cess to code memory an	d enable writes.
0000 6A F8 CLRF TBLPTRU 0000 6A F7 CLRF TBLPTRH 0000 6A F6 CLRF TBLPTRL  Step 3: Enable erase and erase single row.  0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	0000	9C A6	BCF EECON1, CFGS
0000         6A F7         CLRF TBLPTRH           0000         6A F6         CLRF TBLPTRL           Step 3: Enable erase and erase single row.           0000         88 A6         BSF EECON1, FREE           0000         82 A6         BSF EECON1, WR	Step 2: Point to f	irst row in code memory.	
0000 88 A6 BSF EECON1, FREE 0000 82 A6 BSF EECON1, WR	0000	6A F7	CLRF TBLPTRH
0000 82 A6 BSF EECON1, WR	Step 3: Enable e	rase and erase single ro	w.
	0000	82 A6	BSF EECON1, WR

#### FIGURE 3-3: SINGLE ROW ERASE CODE MEMORY FLOW

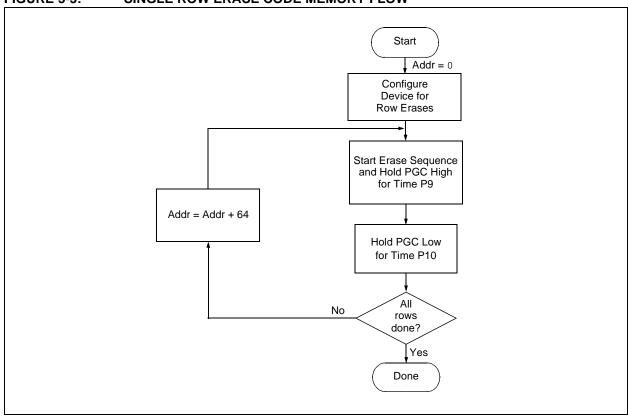


FIGURE 3-4: PROGRAM CODE MEMORY FLOW

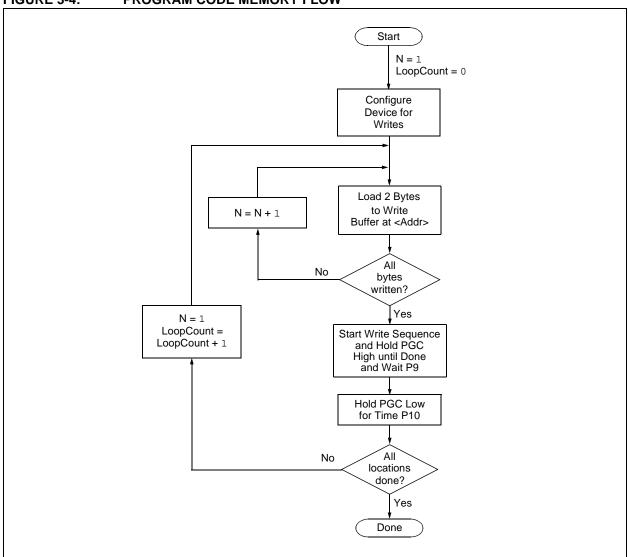


FIGURE 3-5: TABLE WRITE AND START PROGRAMMING INSTRUCTION TIMING (1111)

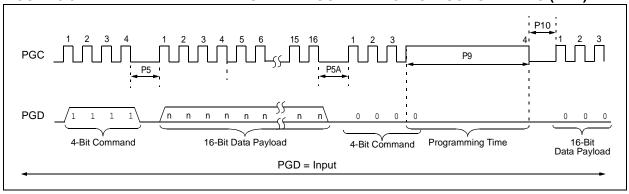


TABLE 3-7: PROGRAMMING DATA MEMORY

4-Bit Command	Data Payload	Core Instruction
Step 1: Direct acc	ess to data EEPROM.	
0000	9E A6 9C A6	BCF EECON1, EEPGD BCF EECON1, CFGS
Step 2: Set the da	ata EEPROM Address Pointe	er.
0000 0000 0000 0000	0E <addr> 6E A9 0E <addrh> 6E AA</addrh></addr>	MOVLW <addr> MOVWF EEADR MOVLW <addrh> MOVWF EEADRH</addrh></addr>
Step 3: Load the	data to be written.	
0000 0000	OE <data> 6E A8</data>	MOVLW <data> MOVWF EEDATA</data>
Step 4: Enable me	emory writes.	
0000	84 A6	BSF EECON1, WREN
Step 5: Initiate wri	ite.	
0000	82 A6	BSF EECON1, WR
Step 6: Poll WR b	it, repeat until the bit is clear	1
0000 0000 0000 0010	50 A6 6E F5 00 00 <msb><lsb></lsb></msb>	MOVF EECON1, W, 0 MOVWF TABLAT NOP Shift out data(1)
Step 7: Hold PGC	low for time P10.	
Step 8: Disable w	rites.	
0000	94 A6	BCF EECON1, WREN
Repeat Steps 2 th	rough 8 to write more data.	

Note 1: See Figure 4-4 for details on shift out data timing.

#### 3.4 ID Location Programming

The ID locations are programmed much like the code memory. The ID registers are mapped in addresses, 200000h through 200007h. These locations read out normally even after code protection.

Note: The user only needs to fill the first 8 bytes of the write buffer in order to write the ID locations.

Table 3-8 demonstrates the code sequence required to write the ID locations.

In order to modify the ID locations, refer to the methodology described in **Section 3.2.1 "Modifying Code Memory"**. As with code memory, the ID locations must be erased before being modified.

TABLE 3-8: WRITE ID SEQUENCE

4-Bit Command	Data Payload	Core Instruction
Step 1: Direct acc	ess to code memory and en	nable writes.
0000	8E A6 9C A6	BSF EECON1, EEPGD BCF EECON1, CFGS
Step 2: Load write	buffer with 8 bytes and writ	te.
0000 0000 0000 0000 0000 0000 1101	0E 20 6E F8 0E 00 6E F7 0E 00 6E F6 <msb><lsb></lsb></msb>	MOVLW 20h MOVWF TBLPTRU MOVLW 00h MOVWF TBLPTRH MOVLW 00h MOVWF TBLPTRL Write 2 bytes and post-increment address by 2.
1101 1101 1111 0000	<msb><lsb> <msb><lsb> <msb><lsb> 00 00</lsb></msb></lsb></msb></lsb></msb>	Write 2 bytes and post-increment address by 2. Write 2 bytes and post-increment address by 2. Write 2 bytes and start programming. NOP - hold PGC high for time P9 and low for time P10.

#### 3.5 Boot Block Programming

The code sequence detailed in Table 3-5 should be used, except that the address used in "Step 2" will be in the range of 000000h to 0007FFh.

#### 3.6 Configuration Bits Programming

Unlike code memory, the Configuration bits are programmed a byte at a time. The Table Write, Begin Programming 4-bit command ('1111') is used, but only eight bits of the following 16-bit payload will be written. The LSB of the payload will be written to even addresses and the MSB will be written to odd addresses. The code sequence to program two consecutive configuration locations is shown in Table 3-9.

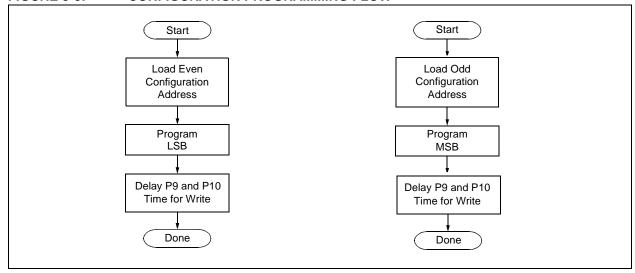
**Note:** The address must be explicitly written for each byte programmed. The addresses can not be incremented in this mode.

TABLE 3-9: SET ADDRESS POINTER TO CONFIGURATION LOCATION

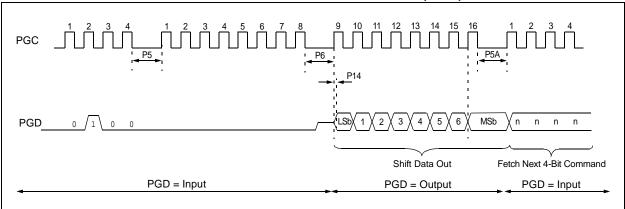
4-Bit Command	Data Payload	Core Instruction
Step 1: Enable wr	ites and direct access to cor	nfiguration memory.
0000	8E A6 8C A6	BSF EECON1, EEPGD BSF EECON1, CFGS
		e to be written. Write even/odd addresses. <sup>(1)</sup>
0000	0E 30	MOVLW 30h
0000	6E F8	MOVWF TBLPTRU
0000	0E 00	MOVLW 00h
0000	6E F7	MOVWF TBLPRTH
0000	0E 00	MOVLW 00h
0000	6E F6	MOVWF TBLPTRL
1111	<msb ignored=""><lsb></lsb></msb>	Load 2 bytes and start programming.
0000	00 00	NOP - hold PGC high for time P9 and low for time P10.
0000	0E 01	MOVLW 01h
0000	6E F6	MOVWF TBLPTRL
1111	<msb><lsb ignored=""></lsb></msb>	Load 2 bytes and start programming.
0000	00 00	NOP - hold PGC high for time P9 and low for time P10.

Note 1: Enabling the write protection of Configuration bits (WRTC = 0 in CONFIG6H) will prevent further writing of the Configuration bits. Always write all the Configuration bits before enabling the write protection for Configuration bits.

#### FIGURE 3-8: CONFIGURATION PROGRAMMING FLOW



#### FIGURE 4-4: SHIFT OUT DATA HOLDING REGISTER TIMING (0010)



#### 4.5 Verify Data EEPROM

A data EEPROM address may be read via a sequence of core instructions (4-bit command, '0000') and then output on PGD via the 4-bit command, '0010' (TABLAT register). The result may then be immediately compared to the appropriate data in the programmer's memory for verification. Refer to **Section 4.4 "Read Data EEPROM Memory"** for implementation details of reading data EEPROM.

#### 4.6 Blank Check

The term Blank Check means to verify that the device has no programmed memory cells. All memories must be verified: code memory, data EEPROM, ID locations and Configuration bits. The Device ID registers (3FFFFEh:3FFFFh) should be ignored.

A "blank" or "erased" memory cell will read as '1'. Therefore, Blank Checking a device merely means to verify that all bytes read as FFh, except the Configuration bits. Unused (reserved) Configuration bits will read '0' (programmed). Refer to Figure 4-5 for blank configuration expect data for the various PIC18F2XXX/4XXX Family devices.

Given that Blank Checking is merely code and data EEPROM verification with FFh expect data, refer to Section 4.4 "Read Data EEPROM Memory" and Section 4.2 "Verify Code Memory and ID Locations" for implementation details.

FIGURE 4-5: BLANK CHECK FLOW

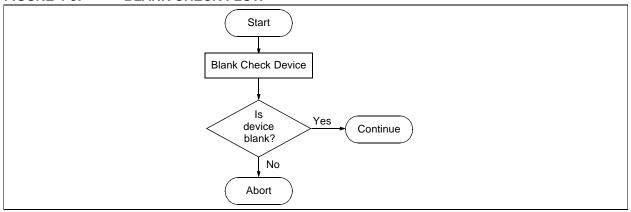


TABLE 5-3: PIC18F2XXX/4XXX FAMILY BIT DESCRIPTIONS (CONTINUED)

Bit Name	Configuration Words	Description
PLLDIV<2:0>	CONFIG1L	Oscillator Selection bits (PIC18F2455/2550/4455/4550, PIC18F2458/2553/4458/4553 and PIC18F2450/4450 devices only)
		Divider must be selected to provide a 4 MHz input into the 96 MHz PLL:  111 = Oscillator divided by 12 (48 MHz input)  110 = Oscillator divided by 10 (40 MHz input)  101 = Oscillator divided by 6 (24 MHz input)  100 = Oscillator divided by 5 (20 MHz input)  011 = Oscillator divided by 4 (16 MHz input)  010 = Oscillator divided by 3 (12 MHz input)  001 = Oscillator divided by 2 (8 MHz input)  000 = No divide - oscillator used directly (4 MHz input)
VREGEN	CONFIG2L	USB Voltage Regulator Enable bit (PIC18F2455/2550/4455/4550, PIC18F2458/2553/4458/4553 and PIC18F2450/4450 devices only)  1 = USB voltage regulator is enabled 0 = USB voltage regulator is disabled
BORV<1:0>	CONFIG2L	Brown-out Reset Voltage bits  11 = VBOR is set to 2.0V  10 = VBOR is set to 2.7V  01 = VBOR is set to 4.2V  00 = VBOR is set to 4.5V
BOREN<1:0>	CONFIG2L	Brown-out Reset Enable bits  11 = Brown-out Reset is enabled in hardware only (SBOREN is disabled)  10 = Brown-out Reset is enabled in hardware only and disabled in Sleep mode SBOREN is disabled)  01 = Brown-out Reset is enabled and controlled by software (SBOREN is enabled)  00 = Brown-out Reset is disabled in hardware and software
PWRTEN	CONFIG2L	Power-up Timer Enable bit  1 = PWRT is disabled  0 = PWRT is enabled
WDPS<3:0>	CONFIG2H	Watchdog Timer Postscaler Select bits  1111 = 1:32,768  1110 = 1:16,384  1101 = 1:8,192  1100 = 1:4,096  1011 = 1:2,048  1010 = 1:512  1000 = 1:256  0111 = 1:128  0110 = 1:64  0101 = 1:32  0100 = 1:16  0011 = 1:8  0010 = 1:4  0001 = 1:2  0000 = 1:1

**Note 1:** The BBSIZ bits, BBSIZ<1:0> and BBSIZ<2:1> bits, cannot be changed once any of the following code-protect bits are enabled: CPB or CP0, WRTB or WRT0, EBTRB or EBTR0.

<sup>2:</sup> Not available in PIC18FXX8X and PIC18F2450/4450 devices.

#### 5.3 Single-Supply ICSP Programming

The LVP bit in Configuration register, CONFIG4L, enables Single-Supply (Low-Voltage) ICSP Programming. The LVP bit defaults to a '1' (enabled) from the factory.

If Single-Supply Programming mode is not used, the LVP bit can be programmed to a '0' and RB5/PGM becomes a digital I/O pin. However, the LVP bit may only be programmed by entering the High-Voltage ICSP mode, where MCLR/VPP/RE3 is raised to VIHH. Once the LVP bit is programmed to a '0', only the High-Voltage ICSP mode is available and only the High-Voltage ICSP mode can be used to program the device.

- **Note 1:** The High-Voltage ICSP mode is always available, regardless of the state of the LVP bit, by applying VIHH to the MCLR/VPP/RE3 pin.
  - 2: While in Low-Voltage ICSP mode, the RB5 pin can no longer be used as a general purpose I/O.

#### 5.4 Embedding Configuration Word Information in the HEX File

To allow portability of code, a PIC18F2XXX/4XXX Family programmer is required to read the Configuration Word locations from the hex file. If Configuration Word information is not present in the hex file, then a simple warning message should be issued. Similarly, while saving a hex file, all Configuration Word information must be included. An option to not include the Configuration Word information may be provided. When embedding Configuration Word information in the hex file, it should start at address, 300000h.

Microchip Technology Inc. feels strongly that this feature is important for the benefit of the end customer.

#### 5.5 Embedding Data EEPROM Information In the HEX File

To allow portability of code, a PIC18F2XXX/4XXX Family programmer is required to read the data EEPROM information from the hex file. If data EEPROM information is not present, a simple warning message should be issued. Similarly, when saving a hex file, all data EEPROM information must be included. An option to not include the data EEPROM information may be provided. When embedding data EEPROM information in the hex file, it should start at address, F00000h.

Microchip Technology Inc. believes that this feature is important for the benefit of the end customer.

#### 5.6 Checksum Computation

The checksum is calculated by summing the following:

- · The contents of all code memory locations
- · The Configuration Words, appropriately masked
- ID locations (if any block is code-protected)

The Least Significant 16 bits of this sum is the checksum. The contents of the data EEPROM are not used.

#### 5.6.1 PROGRAM MEMORY

When program memory contents are summed, each 16-bit word is added to the checksum. The contents of program memory, from 000000h to the end of the last program memory block, are used for this calculation. Overflows from bit 15 may be ignored.

#### 5.6.2 CONFIGURATION WORDS

For checksum calculations, unimplemented bits in Configuration Words should be ignored as such bits always read back as '1's. Each 8-bit Configuration Word is ANDed with a corresponding mask to prevent unused bits from affecting checksum calculations.

The mask contains a '0' in unimplemented bit positions, or a '1' where a choice can be made. When ANDed with the value read out of a Configuration Word, only implemented bits remain. A list of suitable masks is provided in Table 5-5.

TABLE 5-4: DEVICE BLOCK LOCATIONS AND SIZES (CONTINUED)

	Memory			Ending Address								Size (Bytes)				
Device	Size (Bytes)	Pins	Boot Block	Block 0	Block 1	Block 2	Block 3	Block 4	Block 5	Boot Block	Block 0	Remaining Blocks	Device Total			
PIC18F4455	24K	40	0007FF	001FFF	003FFF	005FFF	_	_	_	2048	6144	16384	24576			
PIC18F4458	24K	40	0007FF	001FFF	003FFF	005FFF	_	_	_	2048	6144	16384	24576			
PIC18F4480	16K	40	0007FF	001FFF	003FFF					2048	6144	8192	16384			
PIC 18F4480	TON	40	000FFF	OUTFFF	003FFF	_	_	_	_	4096	4096	8192	16384			
PIC18F4510	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768			
PIC18F4515	48K	40	0007FF	003FFF	007FFF	00BFFF	_	_	_	2048	14336	32768	49152			
PIC18F4520	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	14336	16384	32768			
PIC18F4523	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	14336	16384	32768			
PIC18F4525	48K	40	0007FF	003FFF	007FFF	00BFFF	_	_	_	2048	14336	32768	49152			
PIC18F4550	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768			
PIC18F4553	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF	_	_	2048	6144	24576	32768			
PIC18F4580	32K	40	0007FF	001FFF	003FFF	005FFF	007FFF			2048	6144	24576	22760			
PIC 10F4500	32N	40	000FFF	OUTEFF	003FFF	UUSFFF	007FFF	_	_	4096	4096	24376	32768			
			0007FF							2048	14336		49152			
PIC18F4585	48K	40	000FFF	003FFF	007FFF	00BFFF	_	_		4096	12288	32768				
			001FFF							8192	8192					
PIC18F4610	64K	40	0007FF	003FFF	007FFF	00BFFF	00FFFF	_	_	2048	14336	49152	65536			
PIC18F4620	64K	40	0007FF	003FFF	007FFF	00BFFF	00FFFF	_	_	2048	14336	49152	65536			
			0007FF							2048	14336					
PIC18F4680	64K	40	000FFF	003FFF	007FFF	00BFFF	00FFFF	_	_	4096	12288	49152	65536			
			001FFF							8192	8192					
			0007FF							2048	14336	65536				
PIC18F4682	80K	40	000FFF	003FFF	007FFF	00BFFF	00FFFF	013FFF	_	4096	12288		81920			
			001FFF							8192	8192					
			0007FF							2048	14336	81920	98304			
PIC18F4685	96K	44	000FFF	003FFF	007FFF	00BFFF	00FFFF	013FFF	017FFF	4096	12288					
			001FFF							8192	8192					

**Legend:** — = unimplemented.

TABLE 5-5: CONFIGURATION WORD MASKS FOR COMPUTING CHECKSUMS

TABLE 5-5:	CONFIGURATION WORD MASKS FOR COMPUTING CHECKSUMS													
					С	onfigur	ation W	ord (C	ONFIGX	x)				
Davisa	1L	1H	2L	2H	3L	3H	4L	4H	5L	5H	6L	6H	7L	7H
Device	Address (30000xh)													
	0h	1h	2h	3h	4h	5h	6h	7h	8h	9h	Ah	Bh	Ch	Dh
PIC18F2221	00	CF	1F	1F	00	87	F5	00	03	C0	03	E0	03	40
PIC18F2321	00	CF	1F	1F	00	87	F5	00	03	C0	03	E0	03	40
PIC18F2410	00	CF	1F	1F	00	87	C5	00	03	C0	03	E0	03	40
PIC18F2420	00	CF	1F	1F	00	87	C5	00	03	C0	03	E0	03	40
PIC18F2423	00	CF	1F	1F	00	87	C5	00	03	C0	03	E0	03	40
PIC18F2450	3F	CF	3F	1F	00	86	ED	00	03	40	03	60	03	40
PIC18F2455	3F	CF	3F	1F	00	87	E5	00	07	C0	07	E0	07	40
PIC18F2458	3F	CF	3F	1F	00	87	E5	00	07	C0	07	E0	07	40
PIC18F2480	00	CF	1F	1F	00	86	D5	00	03	C0	03	E0	03	40
PIC18F2510	00	1F	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2515	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2520	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2523	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2525	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2550	3F	CF	3F	1F	00	87	E5	00	0F	C0	0F	E0	0F	40
PIC18F2553	3F	CF	3F	1F	00	87	E5	00	0F	C0	0F	E0	0F	40
PIC18F2580	00	CF	1F	1F	00	86	D5	00	0F	C0	0F	E0	0F	40
PIC18F2585	00	CF	1F	1F	00	86	C5	00	0F	C0	0F	E0	0F	40
PIC18F2610	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2620	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F2680	00	CF	1F	1F	00	86	C5	00	0F	C0	0F	E0	0F	40
PIC18F2682	00	CF	1F	1F	00	86	C5	00	3F	C0	3F	E0	3F	40
PIC18F2685	00	CF	1F	1F	00	86	C5	00	3F	C0	3F	E0	3F	40
PIC18F4221	00	CF	1F	1F	00	87	F5	00	03	C0	03	E0	03	40
PIC18F4321	00	CF	1F 1F	1F	00	87	F5	00	03	C0	03	E0	03	40
PIC18F4410 PIC18F4420	00	CF CF	1F	1F	00	87	C5 C5	00	03	C0	03	E0 E0	03	40
PIC18F4420 PIC18F4423	00	CF	1F	1F 1F	00	87 87	C5	00	03	C0	03	E0	03	40 40
PIC18F4450	3F	CF	3F	1F	00	86	ED	00	03	40	03	60	03	40
PIC18F4455	3F	CF	3F	1F	00	87	E5	00	03	C0	03	E0	03	40
PIC18F4458	3F	CF	3F	1F	00	87	E5	00	07	CO	07	E0	07	40
PIC18F4480	00	CF	1F	1F	00	86	D5	00	03	CO	03	E0	03	40
PIC18F4510	00	CF	1F	1F	00	87	C5	00	05 0F	CO	05 0F	E0	05 0F	40
PIC18F4515	00	CF	1F	1F	00	87	C5	00	0F	CO	0F	E0	0F	40
PIC18F4515	00	CF	1F	1F	00	87	C5	00	0F	CO	0F	E0	0F	40
PIC18F4523	00	CF	1F	1F	00	87	C5	00	0F	CO	0F	E0	0F	40
PIC18F4525	00	CF	1F	1F	00	87	C5	00	0F	CO	0F	E0	0F	40
PIC18F4550	3F	CF	3F	1F	00	87	E5	00	0F	CO	0F	E0	0F	40
PIC18F4553	3F	CF	3F	1F	00	87	E5	00	0F	CO	0F	E0	0F	40
PIC18F4580	00	CF	1F	1F	00	86	D5	00	0F	CO	0F	E0	0F	40
PIC18F4585	00	CF	1F	1F	00	86	C5	00	0F	CO	0F	E0	0F	40
PIC18F4610	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
		olle ere i			00	L 01		00	U	- 50	l oi		l oi	70

**Legend:** Shaded cells are unimplemented.

TABLE 5-5: CONFIGURATION WORD MASKS FOR COMPUTING CHECKSUMS (CONTINUED)

Device	Configuration Word (CONFIGxx)													
	1L	1H	2L	2H	3L	3H	4L	4H	5L	5H	6L	6H	7L	7H
	Address (30000xh)													
	0h	1h	2h	3h	4h	5h	6h	7h	8h	9h	Ah	Bh	Ch	Dh
PIC18F4620	00	CF	1F	1F	00	87	C5	00	0F	C0	0F	E0	0F	40
PIC18F4680	00	CF	1F	1F	00	86	C5	00	0F	C0	0F	E0	0F	40
PIC18F4682	00	CF	1F	1F	00	86	C5	00	3F	C0	3F	E0	3F	40
PIC18F4685	00	CF	1F	1F	00	86	C5	00	3F	C0	3F	E0	3F	40

Legend: Shaded cells are unimplemented.

# 6.0 AC/DC CHARACTERISTICS TIMING REQUIREMENTS FOR PROGRAM/VERIFY TEST MODE

**Standard Operating Conditions** 

Operating Temperature: 25°C is recommended

Operat	ing rem	perature: 25°C is recommended	<u> </u>	1	1	i
Param No.	Sym	Characteristic	Min	Max	Units	Conditions
D110	VIHH	High-Voltage Programming Voltage on MCLR/Vpp/RE3	VDD + 4.0	12.5	V	(Note 2)
D110A	VIHL	Low-Voltage Programming Voltage on MCLR/VPP/RE3	2.00	5.50	V	(Note 2)
D111	VDD	Supply Voltage During Programming	2.00	5.50	V	Externally timed, Row Erases and all writes
			3.0	5.50	V	Self-timed, Bulk Erases only (Note 3)
D112	IPP	Programming Current on MCLR/VPP/RE3	_	300	μΑ	(Note 2)
D113	IDDP	Supply Current During Programming	_	10	mA	
D031	VIL	Input Low Voltage	Vss	0.2 VDD	V	
D041	VIH	Input High Voltage	0.8 VDD	VDD	V	
D080	Vol	Output Low Voltage	_	0.6	V	IOL = 8.5 mA @ 4.5V
D090	Vон	Output High Voltage	VDD - 0.7	_	V	IOH = -3.0 mA @ 4.5V
D012	Сю	Capacitive Loading on I/O pin (PGD)	_	50	pF	To meet AC specifications
	•					
P1	TR	MCLR/VPP/RE3 Rise Time to Enter Program/Verify mode	_	1.0	μS	(Notes 1, 2)
P2	TPGC	Serial Clock (PGC) Period	100	_	ns	VDD = 5.0V
			1	_	μS	VDD = 2.0V
P2A TPGCL	Serial Clock (PGC) Low Time	40	_	ns	VDD = 5.0V	
			400	_	ns	VDD = 2.0V
P2B	TPGCH	Serial Clock (PGC) High Time	40	_	ns	VDD = 5.0V
			400	_	ns	VDD = 2.0V
P3	TSET1	Input Data Setup Time to Serial Clock ↓	15	_	ns	
P4	THLD1	Input Data Hold Time from PGC ↓	15	_	ns	
P5	TDLY1	Delay Between 4-Bit Command and Command Operand	40	_	ns	
P5A	TDLY1A	Delay Between 4-Bit Command Operand and Next 4-Bit Command	40	_	ns	
P6	TDLY2	Delay Between Last PGC ↓ of Command Byte to First PGC ↑ of Read of Data Word	20	_	ns	
P9	TDLY5	PGC High Time (minimum programming time)	1	_	ms	Externally timed
P10	TDLY6	PGC Low Time After Programming (high-voltage discharge time)	100	_	μS	
P11	TDLY7	Delay to Allow Self-Timed Data Write or Bulk Erase to Occur	5	_	ms	

Note 1: Do not allow excess time when transitioning MCLR between VIL and VIHH. This can cause spurious program executions to occur. The maximum transition time is:

<sup>1</sup> TCY + TPWRT (if enabled) + 1024 Tosc (for LP, HS, HS/PLL and XT modes only) +

<sup>2</sup> ms (for HS/PLL mode only) + 1.5  $\mu$ s (for EC mode only)

where TCY is the instruction cycle time, TPWRT is the Power-up Timer period and ToSC is the oscillator period. For specific values, refer to the Electrical Characteristics section of the device data sheet for the particular device.

<sup>2:</sup> When ICPRT = 1, this specification also applies to ICVPP.

<sup>3:</sup> At 0°C-50°C.



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